

RTC Module With 512Kx8 NVSRAM

Features

- ► Integrated SRAM, real-time clock, crystal, power-fail control circuit, and battery
- ► Real-Time Clock counts seconds through years in BCD format
- RAM-like clock access
- ► Pin-compatible with industrystandard 512K x 8 SRAMs
- Unlimited write cycles
- ► 10-year minimum data retention and clock operation in the absence of power
- Automatic power-fail chip deselect and write-protection
- ► Software clock calibration for greater than ± 1 minute per month accuracy

General Description

The bq4850Y RTC Module is a nonvolatile 4,194,304-bit SRAM organized as 524,288 words by 8 bits with an integral accessible real-time clock.

The device combines an internal lithium battery, quartz crystal, clock and power-fail chip, and a full CMOS SRAM in a plastic 32-pin DIP module. The RTC Module directly replaces industry-standard SRAMs and also fits into many EPROM and EE-PROM sockets without any requirement for special write timing or limitations on the number of write cycles.

Registers for the real-time clock, alarm and other special functions are located in registers 7FFF8h-7FFFFh of the memory array.

The clock and alarm registers are dual-port read/write SRAM locations that are updated once per second by a clock control circuit from the internal clock counters. The dual-port registers allow clock updates to occur without interrupting normal access to the rest of the SRAM array.

The bq4850Y also contains a powerfail-detect circuit. The circuit deselects the device whenever V_{CC} falls below tolerance, providing a high degree of data security. The battery is electrically isolated when shipped from the factory to provide maximum battery capacity. The battery remains disconnected until the first application of V_{CC}.

Pin Connections

A18 🗆		32 🗆 VCC
A16 🗆	2	31 🛛 A ₁₅
A14 🗆	3	30 🗖 A ₁₇
A ₁₂ 🗆	4	29 🛛 🚾
A7 🗆	5	28 🗆 A ₁₃
A6 🗆	6	27 🗖 A8
A5 🗆	7	26 🛛 Ag
A4 🗆	8	25 🛛 A ₁₁
A3 🗆	9	24 🛛 OE
A2 🗆	10	23 🛛 A ₁₀
A1 🗆	11	22 🛛 CE
A0 🗆	12	21 🛛 DQ7
DQ0 [13	20 🗖 DQ6
DQ1 🗆	14	19 🗖 DQ5
DQ ₂	15	18 🗖 DQ4
Vss 🗆	16	17 🗖 DQ3
	32-Pin DIP N	
		PN485001.eps

A0-A18	Address input
$\overline{\text{CE}}$	Chip enable
$\overline{\mathrm{WE}}$	Write enable
$\overline{\text{OE}}$	Output enable
DQ0-DQ7	Data in/data out
V _{CC}	+5 volts
V _{SS}	Ground

SLUS057A- January 2005

Functional Description

Figure 1 is a block diagram of the bq4850Y. The following sections describe the bq4850Y functional operation,

including memory and clock interface, and data-retention modes.

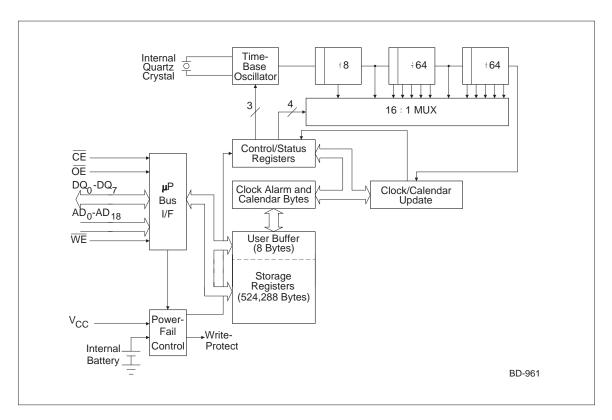


Figure 1. Block Diagram

Truth Table

V _{cc}	CE	ŌE	WE Mode		DQ	Power
< V _{CC} (max.)	V_{IH}	Х	Х	Deselect	High Z	Standby
	VIL	Х	VIL	Write	D _{IN}	Active
> V _{CC} (min.)	VIL	VIL	V _{IH}	Read	Dout	Active
	VIL	VIH	VIH	Read	High Z	Active
$< V_{PFD}$ (min.) $> V_{SO}$	Х	Х	Х	Deselect	High Z	CMOS standby
$\leq V_{SO}$	Х	Х	Х	Deselect	High Z	Battery-backup mode

SLUS057A- January 2005

Address Map

The bq4850Y provides 8 bytes of clock and control status registers and 524,288 bytes of storage RAM.

Figure 2 illustrates the address map for the bq4850Y. Table 1 is a map of the bq4850Y registers.

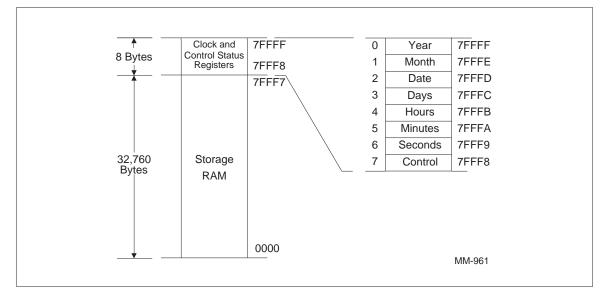


Figure 2. Address Map

Address	D7	D6	D5	D4	D3	D2	D1	D0	Range (h)	Register	
7FFFF	TFF 10 Years			Year			00–99	Year			
7FFFE	Х	Х	Х	10 Month	Month				01–12	Month	
7FFFD	Х	X	10	Date	Date			Date		01-31	Date
7FFFC	Х	FTE	Х	X	Х	X Day			01–07	Days	
7FFFB	Х	Х	10	Hours	Hours				00-23	Hours	
7FFFA	Х		10 Minutes		Minutes				00–59	Minutes	
7FFF9	OSC		10 Secon	conds Seconds		Seconds			00–59	Seconds	
7FFF8	W	R	S		Calibration				00-31	Control	

Table 1. bq4850Y Clock and Control Register Map

Notes: X = Unused bits; can be written and read. Clock/Calendar data in 24-hour BCD format. OSC = 1 stops the clock oscillator.

SLUS057A- January 2005

Memory Interface

Read Mode

The bq4850Y is in read mode whenever \overline{OE} (output enable) is low and \overline{CE} (chip enable) is low. The device architecture allows ripple-through access of data from eight of 4,194,304 locations in the static storage array. Thus, the unique address specified by the 19 address inputs defines which one of the 524,288 bytes of data is to be accessed. Valid data is available at the data I/O pins within t_{AA} (address access time) after the last address input signal is stable, providing that the \overline{CE} and \overline{OE} (output enable) access times are also satisfied. If the \overline{CE} and \overline{OE} after the latter of chip enable access time (t_{ACE}) or output enable access time (t_{OE}).

 \overline{CE} and \overline{OE} control the state of the eight three-state data I/O signals. If the outputs are activated before $t_{AA},$ the data lines are driven to an indeterminate state until t_{AA} . If the address inputs are changed while \overline{CE} and \overline{OE} remain low, output data remains valid for t_{OH} (output data hold time), but goes indeterminate until the next address access.

Write Mode

The bq4850Y is in write mode whenever \overline{WE} and \overline{CE} are active. The start of a write is referenced from the latter-occurring falling edge of \overline{WE} or \overline{CE} . A write is terminated by the earlier rising edge of \overline{WE} or \overline{CE} . The addresses must be held valid throughout the cycle. \overline{CE} or \overline{WE} must return high for a minimum of t_{WR2} from \overline{CE} or t_{WR1} from \overline{WE} prior to the initiation of another read or write cycle.

Data-in must be valid t_{DW} prior to the end of write and remain valid for t_{DH1} or t_{DH2} afterward. \overrightarrow{OE} should be kept high during write cycles to avoid bus contention; although, if the output bus has been activated by a low on \overrightarrow{CE} and \overrightarrow{OE} , a low on \overrightarrow{WE} disables the outputs t_{WZ} after \overrightarrow{WE} falls.

Data-Retention Mode

With valid V_{CC} applied, the bq4850Y operates as a conventional static RAM. Should the supply voltage decay, the RAM automatically power-fail deselects, write-protecting itself t_{WPT} after V_{CC} falls below V_{PFD}. All outputs become high impedance, and all inputs are treated as "don't care."

If power-fail detection occurs during a valid access, the memory cycle continues to completion. If the memory cycle fails to terminate within time t_{WPT} , write-protection takes place. When V_{CC} drops below V_{SO} , the control circuit switches power to the internal energy source, which preserves data.

The internal coin cell maintains data in the bq4850Y after the initial application of V_{CC} for an accumulated period of at least 10 years when V_{CC} is less than V_{SO} . As system power returns and Vcc rises above V_{SO} , the battery is disconnected, and the power supply is switched to external V_{CC} . Write-protection continues for t_{CER} after V_{CC} reaches V_{PFD} to allow for processor stabilization. After t_{CER} , normal RAM operation can resume.

Clock Interface

Reading the Clock

The interface to the clock and control registers of the bq4850Y is the same as that for the general-purpose storage memory. Once every second, the user-accessible clock/calendar locations are updated simultaneously from the internal real time counters. To prevent reading data in transition, updates to the bq4850Y clock registers should be halted. Updating is halted by setting the read bit D6 of the control register to 1. As long as the read bit is 1, updates to user-accessible clock locations are inhibited. Once the frozen clock information is retrieved by reading the appropriate clock memory locations, the read bit should be reset to 0 in order to allow updates to occur from the internal counters. Because the internal counters are not halted by setting the read bit, reading the clock locations has no effect on clock accuracy. Once the read bit is reset to 0, within one second the internal registers update the user-accessible registers with the correct time. A halt command issued during a clock update allows the update to occur before freezing the data.

Setting the Clock

Bit D7 of the control register is the write bit. Like the read bit, the write bit when set to a 1 halts updates to the clock/calendar memory locations. Once frozen, the locations can be written with the desired information in 24-hour BCD format. Resetting the write bit to 0 causes the written values to be transferred to the internal clock counters and allows updates to the user-accessible registers to resume within one second. Use the write bit, D7, only when updating the time registers (7FFFF–7FFF9).

Stopping and Starting the Clock Oscillator

The OSC bit in the seconds register turns the clock on or off. If the bq4850Y is to spend a significant period of time in storage, the clock oscillator can be turned off to preserve battery capacity. OSC set to 1 stops the clock oscillator. When OSC is reset to 0, the clock oscillator is turned on and clock updates to user-accessible memory locations occur within one second.

The OSC bit is set to 1 when shipped from the Benchmarq factory.

SLUS057A- January 2005

Calibrating the Clock

The bq4850Y real-time clock is driven by a quartz controlled oscillator with a nominal frequency of 32,768 Hz. The quartz crystal is contained within the bq4850Y package along with the battery. The clock accuracy of the bq4850Y module is tested to be within 20ppm or about 1 minute per month at 25°C. The oscillation rates of crystals change with temperature as Figure 3 shows. To compensate for the frequency shift, the bq4850Y offers onboard software clock calibration. The user can adjust the calibration based on the typical operating temperature of individual applications.

The software calibration bits are located in the control register. Bits D0–D4 control the magnitude of correction, and bit D5 the direction (positive or negative) of correction. Assuming that the oscillator is running at exactly 32,786 Hz, each calibration step of D0–D4 adjusts the clock rate by ± 4.068 ppm (± 10.7 seconds per month) or ± 2.034 ppm (± 5.35 seconds per month) depending on the value of the sign bit D5. When the sign bit is 1, positive adjustment occurs; a 0 activates negative adjustment. The total range of clock calibration is ± 5.5 or ± 2.75 minutes per month.

Two methods can be used to ascertain how much calibration a given bq4850Y may require in a system. The first involves simply setting the clock, letting it run for a month, and then comparing the time to an accurate known reference like WWV radio broadcasts. Based on the variation to the standard, the end user can adjust the clock to match the system's environment even after the product is packaged in a non-serviceable enclosure. The only requirement is a utility that allows the end user to access the calibration bits in the control register.

The second approach uses a bq4850Y test mode. When the frequency test mode enable bit FTE in the days reg-

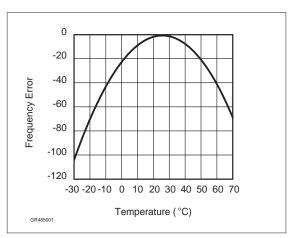


Figure 3. Frequency Error

ister is set to a 1, and the oscillator is running at exactly 32,768 Hz, the LSB of the seconds register toggles at 512 Hz. Any deviation from 512 Hz indicates the degree and direction of oscillator frequency shift at the test temperature. For example, a reading of 512.01024 Hz indicates a (1E6*0.01024)/512 or +20 ppm oscillator frequency error, requiring ten steps of negative calibration (10*-2.034 or -20.34) or 001010 to be loaded into the calibration byte for correction. To read the test frequency, the bq4850Y must be selected and held in an extended read of the seconds register, location 7FFF9, without having the read bit set. The frequency appears on DQ0. The FTE bit must be set using the write bit control. The FTE bit must be reset to 0 for normal clock operation to resume.

SLUS057A- January 2005

Absolute Maximum Ratings						
Symbol	Parameter	Value	Unit	Conditions		
V _{CC}	DC voltage applied on $V_{\rm CC}$ relative to $V_{\rm SS}$	-0.3 to 7.0	V			
VT	DC voltage applied on any pin excluding V_{CC} relative to $V_{\rm SS}$	-0.3 to 7.0	V	$V_T\!\le\!V_{CC}+0.3$		
T _{OPR}	Operating temperature	0 to +70	°C	Commercial		
		-40 to + 85	°C	Industrial		
T _{STG}	Storage temperature (V _{CC} off; oscillator off)	-40 to +70	°C	Commercial		
		-40 to + 85	°C	Industrial		
T _{BIAS}	Temperature under bias	-10 to +70	°C	Commercial		
		-40 to + 85	°C	Industrial		
T _{SOLDER}	Soldering temperature	+260	°C	For 10 seconds		

Note: Permanent device damage may occur if **Absolute Maximum Ratings** are exceeded. Functional operation should be limited to the Recommended DC Operating Conditions detailed in this data sheet. Exposure to conditions beyond the operational limits for extended periods of time may affect device reliability.

Recommended DC Operating Conditions (TA = TOPR)

Symbol	Parameter	Minimum	Typical	Maximum	Unit	Notes
Vcc	Supply voltage	4.5	5.0	5.5	V	
Vss	Supply voltage	0	0	0	v	
VIL	Input low voltage	-0.3	-	0.8	v	
V _{IH}	Input high voltage	2.2	-	V _{CC} + 0.3	V	

Note: Typical values indicate operation at $T_A = 25^{\circ}C$.

6

Symbol	Parameter	Minimum	Typical	Maximum	Unit	Conditions/Notes
I _{LI}	Input leakage current	-	-	± 1	μΑ	$V_{IN} = V_{SS}$ to V_{CC}
ILO	Output leakage current	-	-	± 1	μΑ	$\label{eq:eq:cell} \begin{array}{l} \overline{CE} = V_{IH} \mbox{ or } \overline{OE} = V_{IH} \mbox{ or } \\ \overline{WE} = V_{IL} \end{array}$
VOH	Output high voltage	2.4	-	-	V	I _{OH} = -1.0 mA
Vol	Output low voltage	-	-	0.4	V	$I_{OL} = 2.1 \text{ mA}$
I _{SB1}	Standby supply current	-	3	5	mA	$\overline{CE} = V_{IH}$
I _{SB2}	Standby supply current	-	0.1	1	mA	$\label{eq:cell} \begin{split} \overline{CE} &\geq V_{CC} - 0.2V,\\ 0V &\leq V_{IN} \leq \ 0.2V,\\ \text{or} \ V_{IN} \geq V_{CC} - 0.2V \end{split}$
ICC	Operating supply current	-	-	90	mA	$\label{eq:min.cycle, duty = 100\%,} \frac{Min. cycle, duty = 100\%,}{CE = V_{IL}, I_{I/O} = 0mA}$
VPFD	Power-fail-detect voltage	4.30	4.37	4.50	V	
V _{SO}	Supply switch-over voltage	-	3	-	V	

DC Electrical Characteristics (TA = TOPR, VCCmin ≤ VCC ≤ VCCmax)

Note: Typical values indicate operation at $T_A = 25^{\circ}C$, $V_{CC} = 5V$.

Capacitance (T_A = 25°C, F = 1MHz, V_{CC} = 5.0V)

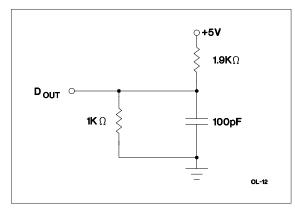
Symbol	Parameter	Minimum	Typical	Maximum	Unit	Conditions
C _{I/O}	Input/output capacitance	-	-	10	pF	Output voltage = 0V
C _{IN}	Input capacitance	-	-	10	pF	Input voltage = 0V

Note: These parameters are sampled and not 100% tested.

SLUS057A- January 2005

AC Test Conditions

Parameter	Test Conditions
Input pulse levels	0V to 3.0V
Input rise and fall times	5 ns
Input and output timing reference levels	1.5 V (unless otherwise specified)
Output load (including scope and jig)	See Figures 4 and 5



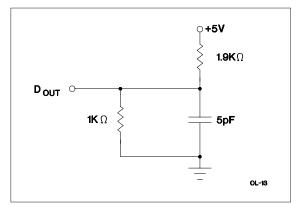


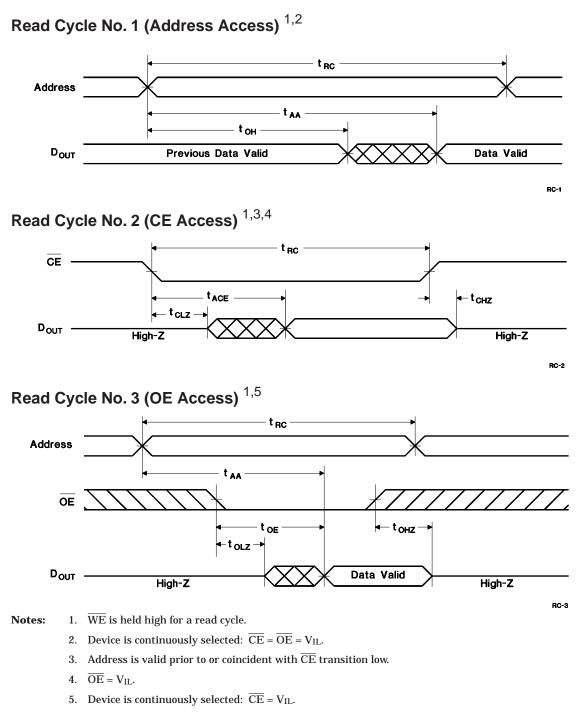
Figure 4. Output Load A

Figure 5. Output Load B

$\label{eq:read} \textit{Read Cycle} ~~ (\texttt{T}_{A} \texttt{= T}_{OPR}, \texttt{VCCmin} \ \leq \texttt{VCC} \leq \texttt{VCCMAX})$

		-85			
Symbol	Parameter	Min.	Max.	Unit	Conditions
t _{RC}	Read cycle time	85	-	ns	
t _{AA}	Address access time	-	85	ns	Output load A
t _{ACE}	Chip enable access time	-	85	ns	Output load A
toE	Output enable to output valid	-	45	ns	Output load A
t _{CLZ}	Chip enable to output in low Z	5	-	ns	Output load B
t _{OLZ}	Output enable to output in low Z	0	-	ns	Output load B
t _{CHZ}	Chip disable to output in high Z	0	35	ns	Output load B
t _{OHZ}	Output disable to output in high Z	0	25	ns	Output load B
toH	Output hold from address change	10	-	ns	Output load A

SLUS057A- January 2005



SLUS057A- January 2005

		-85			
Symbol	Parameter	Min.	Max.	Units	Conditions/Notes
twc	Write cycle time	85	-	ns	
tcw	Chip enable to end of write	75	-	ns	(1)
t _{AW}	Address valid to end of write	75	-	ns	(1)
t _{AS}	Address setup time	0	-	ns	Measured from address valid to begin- ning of write. (2)
t _{WP}	Write pulse width	65	-	ns	Measured from beginning of write to end of write. (1)
t _{WR1}	Write recovery time (write cycle 1)	5	-	ns	Measured from $\overline{\rm WE}$ going high to end of write cycle. (3)
t _{WR2}	Write recovery time (write cycle 2)	15	-	ns	Measured from \overline{CE} going high to end of write cycle. (3)
t _{DW}	Data valid to end of write	35	-	ns	Measured to first low-to-high transition of either \overline{CE} or $\overline{WE}.$
t _{DH1}	Data hold time (write cycle 1)	0	-	ns	Measured from \overline{WE} going high to end of write cycle. (4)
t _{DH2}	Data hold time (write cycle 2)	10	-	ns	Measured from $\overline{\text{CE}}$ going high to end of write cycle. (4)
t _{WZ}	Write enabled to output in high Z	0	30	ns	I/O pins are in output state. (5)
tow	Output active from end of write	0	-	ns	I/O pins are in output state. (5)

Write Cycle (TA = TOPR, VCCMIN \leq VCC \leq VCCMAX)

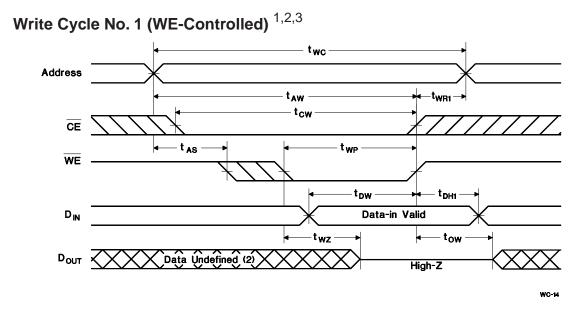
Notes:

1. A write ends at the earlier transition of $\overline{\text{CE}}$ going high and $\overline{\text{WE}}$ going high.

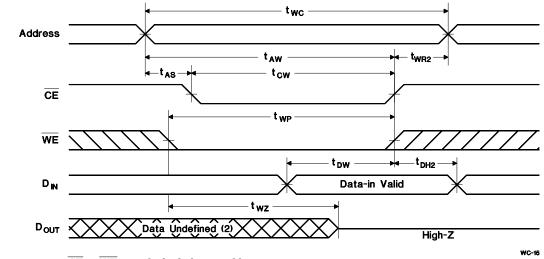
2. A write occurs during the overlap of a low \overline{CE} and a low \overline{WE} . A write begins at the later transition of \overline{CE} going low and \overline{WE} going low.

- 3. Either t_{WR1} or t_{WR2} must be met.
- 4. Either t_{DH1} or t_{DH2} must be met.
- 5. If $\overline{\text{CE}}$ goes low simultaneously with $\overline{\text{WE}}$ going low or after $\overline{\text{WE}}$ going low, the outputs remain in high-impedance state.

SLUS057A- January 2005



Write Cycle No. 2 (CE-Controlled) ^{1,2,3,4,5}





1. $\overline{\text{CE}}$ or $\overline{\text{WE}}$ must be high during address transition.

- 2. Because I/O may be active ($\overline{\text{OE}}$ low) during this period, data input signals of opposite polarity to the outputs must not be applied.
- 3. If \overline{OE} is high, the I/O pins remain in a state of high impedance.
- 4. Either t_{WR1} or t_{WR2} must be met.
- 5. Either t_{DH1} or t_{DH2} must be met.

SLUS057A- January 2005

Symbol	Parameter	Minimum	Typical	Maximum	Unit	Conditions
t _{PF}	V_{CC} slew, 4.50 to 4.20 V $$	300	-	-	μs	
$t_{\rm FS}$	V_{CC} slew, 4.20 to V_{SO}	10	-	-	μs	
t _{PU}	V _{CC} slew, V _{SO} to V _{PFD} (max.)	0	-	-	μs	
t _{CER}	Chip enable recovery time	40	100	200	ms	Time during which SRAM is write-protected after V_{CC} passes V_{FPD} on power-up.
t _{DR}	Data-retention time in absence of V_{CC}	10	-	-	years	$T_{\rm A} = 25^{\circ} {\rm C.} (2)$
t _{WPT}	Write-protect time	40	100	160	μs	Delay after V_{CC} slews down past V_{PFD} before SRAM is write-protected.

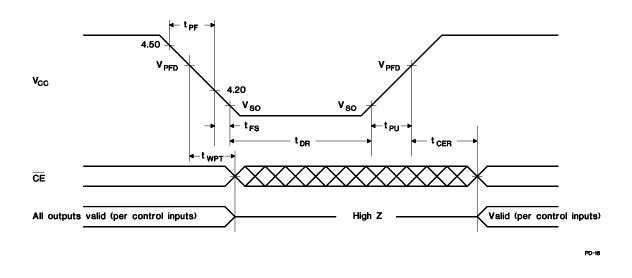
Power-Down/Power-Up Cycle (TA = TOPR)

Notes: 1. Typical values indicate operation at $T_A = 25$ °C, $V_{CC} = 5$ V.

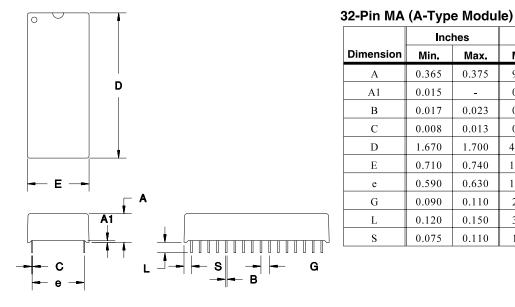
2. Battery is disconnected from circuit until after V_{CC} is applied for the first time. t_{DR} is the accumulated time in absence of power beginning when power is first applied to the device.

Caution: Negative undershoots below the absolute maximum rating of -0.3V in battery-backup mode may affect data integrity.

Power-Down/Power-Up Timing



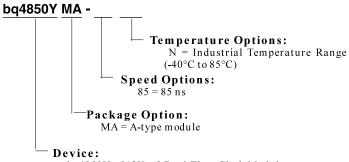
MA: 32-Pin A-Type Module



Millimeters Inches Dimension Min. Min. Max. Max.

А	0.365	0.375	9.27	9.53
A1	0.015	-	0.38	-
В	0.017	0.023	0.43	0.58
С	0.008	0.013	0.20	0.33
D	1.670	1.700	42.42	43.18
Е	0.710	0.740	18.03	18.80
e	0.590	0.630	14.99	16.00
G	0.090	0.110	2.29	2.79
L	0.120	0.150	3.05	3.81
S	0.075	0.110	1.91	2.79

Ordering Information



bq4850Y 512K x 8 Real-Time Clock Module

SLUS057A - Jan. 2005

www.ti.com

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
BQ4850YMA-85	NRND	DIP MOD ULE	MA	32	12	Pb-Free (RoHS)	Call TI	N / A for Pkg Type
BQ4850YMA-85N	ACTIVE	DIP MOD ULE	MB	32	12	Pb-Free (RoHS)	Call TI	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

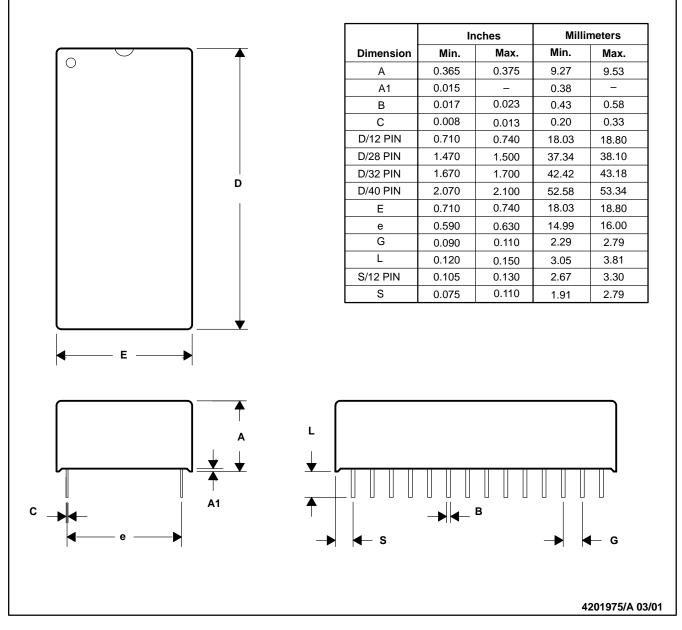
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

MECHANICAL DATA

MPDI061 - MAY 2001

PLASTIC DUAL-IN-LINE

MA (R-PDIP-T**) 28 PINS SHOWN



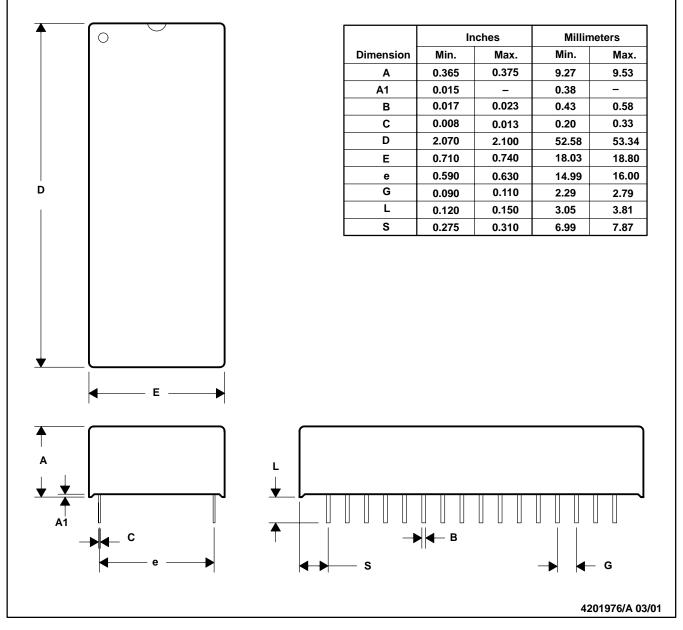
NOTES: A. All linear dimensions are in inches (mm). B. This drawing is subject to change without notice.



MECHANICAL DATA

MPDI062 - MAY 2001

PLASTIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (mm). B. This drawing is subject to change without notice.

MB (R-PDIP-T32)



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DLP® Products	www.dlp.com	Broadband	www.ti.com/broadband
DSP	dsp.ti.com	Digital Control	www.ti.com/digitalcontrol
Clocks and Timers	www.ti.com/clocks	Medical	www.ti.com/medical
Interface	interface.ti.com	Military	www.ti.com/military
Logic	logic.ti.com	Optical Networking	www.ti.com/opticalnetwork
Power Mgmt	power.ti.com	Security	www.ti.com/security
Microcontrollers	microcontroller.ti.com	Telephony	www.ti.com/telephony
RFID	www.ti-rfid.com	Video & Imaging	www.ti.com/video
RF/IF and ZigBee® Solutions	www.ti.com/lprf	Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2009, Texas Instruments Incorporated